

### 25 MIPS, 16 kB Flash, 10-Bit ADC, 24-pin Mixed-Signal MCU

### **Analog Peripherals**

#### 10-Bit ADC

- Programmable throughput up to 200 ksps
- Up to 16 external inputs; programmable as single-ended or differential
- Reference from internal V<sub>RFF</sub>, V<sub>DD</sub>, or external pin
- Internal or external start of conversion sources
- Built-in temperature sensor

#### 10-bit DAC (Current Mode)

#### Comparator

- Programmable hysteresis and response time
- Configurable to generate interrupts or reset
- Low current

#### **On-Chip Debug**

- On-chip debug circuitry facilitates full speed, non-intrusive in-system debug (no emulator required)
- Provides breakpoints, single stepping, watchpoints
- Inspect/modify memory, registers, and stack
- Superior performance to emulation systems using ICE-chips, target pods, and sockets

Supply Voltage: 2.7 to 3.6 V

Temperature Range: -40 to +85 °C

#### High-Speed 8051 µC Core

- Pipelined instruction architecture; executes 70% of instructions in 1 or 2 system clocks
- Up to 25 MIPS throughput with 25 MHz clock
- Expanded interrupt handler

#### Memory

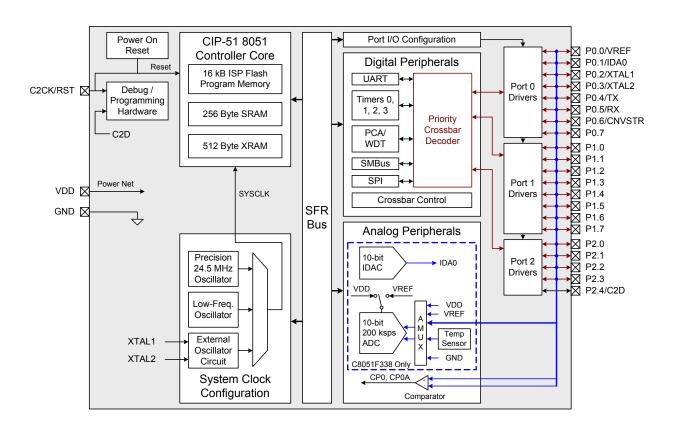
- 768 bytes data RAM
- 16 kB Flash; in-system programmable in 512 byte sectors (512 bytes are reserved)

#### **Digital Peripherals**

- 21 port I/O; all are 5 V tolerant
- Hardware SMBus™ (I<sup>2</sup>C™ compatible), SPI™, and crystaless-UART serial ports available concurrently
- Programmable 16-bit counter/timer array with three capture/compare modules, WDT
- 4 general-purpose 16-bit counter/timers
- Timer with real-time clock mode
- Clock sources
- Two internal oscillators:
  - Precision 24.5 MHz, 2% accuracy over V<sub>DD</sub> and temperature
  - 80 kHz low frequency, low-power
- External oscillator: Crystal, RC, C, or Clock (1 or 2 pin modes)
- Can switch between clock sources on-the-fly
- Suspend mode for maximum power savings with fast wake-up (<1 us)

#### **Package**

- 24-pin QFN



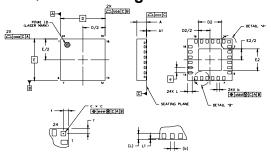


# 25 MIPS, 16 kB Flash, 10-Bit ADC, 24-pin Mixed-Signal MCU

Selected Electrical Specifications ( $T_A = -40 \text{ to } +85 \text{ C}^{\circ}, V_{DD} = 2.7 \text{ V unless otherwise specified}$ )

	Conditions		Тур	Max	Units
Global Characteristics			1		· L
Supply Voltage			_	3.6	V
Supply Current with CPU Active	Clock = 25 MHz	_	TBD	_	mA
	Clock = 1 MHz	_	TBD	_	mA
	Clock = 80 kHz; V <sub>DD</sub> monitor disabled	_	TBD	_	μΑ
	Clock = 32 kHz; V <sub>DD</sub> monitor disabled	_	TBD	_	μΑ
Supply Current (shutdown)	Oscillator off; V <sub>DD</sub> monitor disabled	_	TBD	_	μΑ
Clock Frequency Range			_	25	MHz
Internal Oscillators	·				•
Frequency (OSC0)			24.5	25.0	MHz
Frequency (OSC1)			80	_	kHz
A/D Converter		•			
Resolution					bits
Integral Nonlinearity			±1/2	TBD	LSB
Differential Nonlinearity	Guaranteed monotonic	_	±1/2	TBD	LSB
Signal-to-Noise Plus Distortion			55.5	_	dB
Throughput Rate			_	200	ksps
Input Voltage Range			_	V <sub>REF</sub>	V
D/A Converter		•			
Resolution					bits
Integral Nonlinearity			±1/2	_	LSB
Differential Nonlinearity	Guaranteed monotonic	_	±1/2	TBD	LSB
Output Settling Time			5	_	μs
Comparator		•	1		
Response Time Mode0	(CP+) – (CP–) = 100 mV	_	TBD	_	μs
Current Consumption Mode0			TBD	_	μA
Response Time Mode1	(CP+) - (CP-) = 100 mV	_	TBD	_	μs
Current Consumption Mode1			TBD	_	μA
Response Time Mode2	(CP+) - (CP-) = 100 mV	_	TBD	_	μs
Current Consumption Mode2			TBD	_	μA
Response Time Mode3	(CP+) - (CP-) = 100 mV	_	TBD	_	μs
Current Consumption Mode3			TBD		μA

## **QFN-24 Package Information**



DETAIL "A"				DETAIL "B"			
Dimension	Millimeters			Dimension	Millimeters		
	Min	Nom	Max		Min	Nom	Max
Α	0.80	0.85	0.90	E2	2.00	2.10	2.20
A1	0.00	0.02	0.05	L	0.30	0.40	0.50
b	0.18	0.25	0.30	L1	0.03	0.05	0.08
С	0.19	0.24	0.29	aaa	_	_	0.10
D	4.00 BSC.			bbb	_	_	0.10
D2	2.00	2.10	2.20	CCC	_	_	0.08
е	0.50 BSC.		ddd	_	_	0.10	
f	0.27 BSC		eee	_	_	0.10	
E		4.00 BSC.					

# C8051F338DK Development Kit



#### **Small Form Factor**